

### Over-voltage Protection Thyristor

### Description

DO-214AA P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

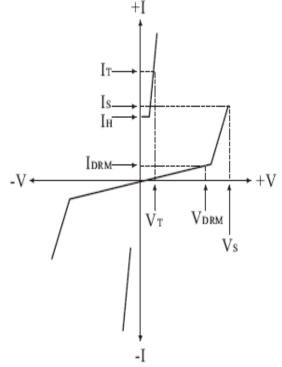
Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- · Have low capacitance, making them ideal for high-speed transmission equipment

### **Electrical Parameters**

Parameter	Definition	
<b>C</b> 0	<b>Off-state Capacitance</b> — typical capacitance	
	measured in off state	
di/dt	Rate of Rise of Current — maximum rated value of	
	the acceptable rate of rise in current over time	
Is	Switching Current — maximum current required to	
	switch to on state	
<b>T</b> DRM	Leakage Current — maximum peak off-state current	
	measured at VDRM	
$\mathbf{I}^{\mathrm{H}}$	Holding Current — minimum current required to	
	maintain on state	
<b>I</b> PP	Peak Pulse Current — maximum rated peak impulse	
	current	-V +
Ι	<b>On-state Current</b> — maximum rated continuous	Γ
	on-state current	/
<b>I</b> TSM	Peak One-cycle Surge Current — maximum rated	/
	one-cycle AC current	/
<b>V</b> S	Switching Voltage — maximum voltage prior to	
	switching to on state	
<b>V</b> DRM	Peak Off-state Voltage — maximum voltage that can	
	be applied while maintaining off state	
VF	On-state Forward Voltage — maximum forward	
	voltage measured at rated on-state current	
VT	<b>On-state Voltage</b> — maximum voltage measured at	
	rated on-state current	

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# **SP5000SA**

**P** Series

ROHS

# Senchip

### **P** Series

ver-voltage Protection Thyristor				SP		ROHS		
ctricalCha	racterist	ics						
Part	Vdrm	Vs	VT	Idrm	Is	Іт	Ін	Co
Number*	Volts	Volts	Volts	µ Amps	mAmps	Amps	mAmps	pF
SP5000SA	440	600	4	5	800	2.2	150	20

\* For surge ratings, see table below.

Notes:

• All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.

• Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Rat:	ings						
Series	Ipp 2/10 μs Amps	IPP 8/20 μs Amps	Ipp 10/160 μs Amps	IPP 10/560 µs Amps	IPP 10/1000 µs Amps	Ітым 60 Hz Amps	di/dt Amps∕µs
А	150	150	90	50	45	20	500
Thermal Co	onsiderations						
Package	DO-214AA/SMB	Symbol		Parameter		Value	Unit
		$T_{ m J}$	Operating	g Junction Ten	perature	-40 to +150	°C
		Ts	Storage Temperature Range			-40 to +150	$^{\circ}\mathrm{C}$
		R o JA	unction to	Ambient on p	rinted circuit	120	°C/W



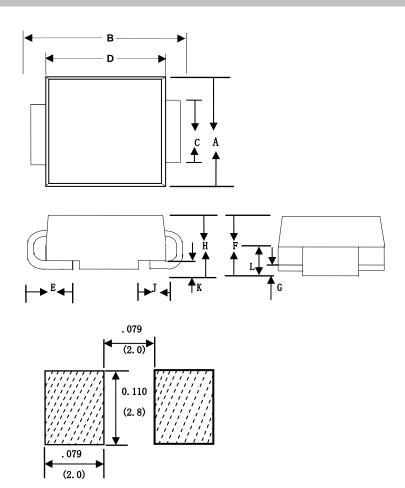
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**SP5000SA** 

ROHS

**P** Series

### Dimensions



SMB
Omb

Dimension	In	ches	Millimeters		
Dimension	MIN MAX		MIN	MAX	
А	0. 134	0. 155	3. 40	3.94	
В	0. 205	0. 22	5. 21	5. 59	
С	0.075	0. 083	1.90	2.11	
D	0. 166	0. 185	4. 22	4. 70	
E	0. 036	0.056	0. 91	1.42	
F	0.073	0. 087	1.85	2.2	
G	0.002	0.008	0. 05	0. 20	
Н	0.077	0.094	1.95	2. 40	
J	0. 043	0. 053	1.09	1.35	
K	0.008	0.014	0. 20	0.35	
L	0. 039	0. 049	0. 99	1.24	

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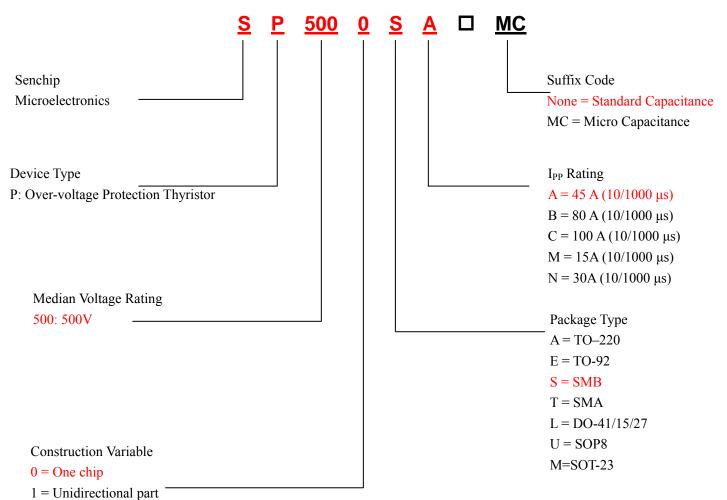
**P** Series

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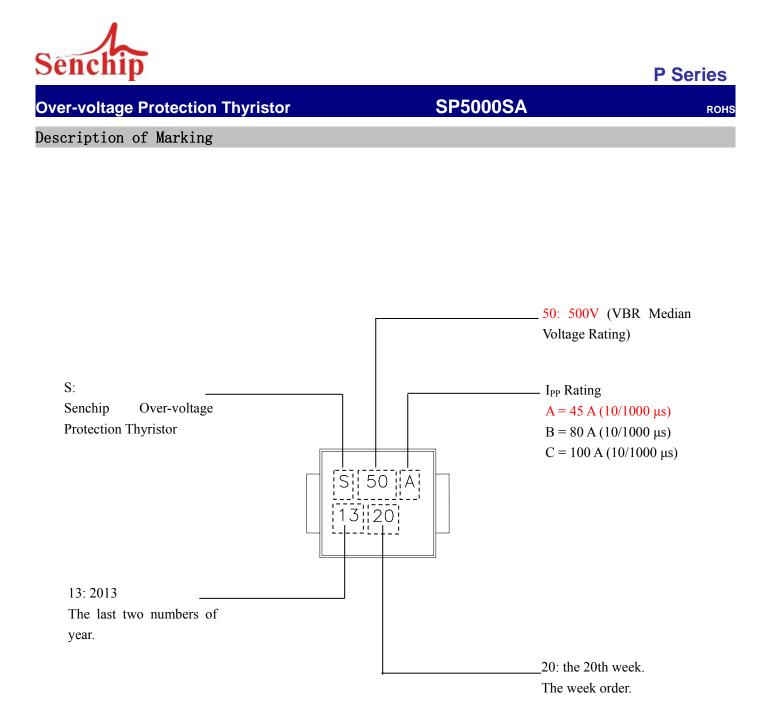
## SP5000SA

### ROHS

### Description of Part Number



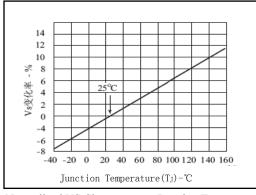
- 2 =Two chips
- 3 = Three chips





Sencnip	P Series		
Over-voltage Protec	tion Thyristor	SP5000SA	ROHS
Summary of Packing	Options		
Package Type	Description	Packing Quantity	Industry Standard
DO-214AA SMB			
	Embossed Carrier Reel Pack	2500 PCS	EIA RS-481

### Thermal Derating Curves



Normalized VS Change versus Junction Temperature

